

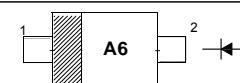
**Applications**

- High-speed switching

**MARKING:**A6

**PINNING**

PIN	DESCRIPTION
1	Cathode
2	Anode



Top View  
Marking Code: "A6"  
Simplified outline SOD-323 and symbol

**Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )**

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	100	V
Reverse Voltage	$V_R$	100	V
Continuous Forward Current	$I_F$	250	mA
Repetitive Peak Forward Current	$I_{FRM}$	500	mA
Non-Repetitive Peak Forward Current	$I_{FSM}$	4 1 0.5	A
t = 1 $\mu\text{s}$ t = 1 ms t = 1 s			
Total Power Dissipation	$P_{tot}$	200	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 65 to + 150	$^\circ\text{C}$

**Characteristics at  $T_a = 25^\circ\text{C}$** 

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 1 \text{ mA}$ at $I_F = 10 \text{ mA}$ at $I_F = 50 \text{ mA}$ at $I_F = 150 \text{ mA}$	$V_F$	0.715 0.855 1 1.25	V
Reverse Current at $V_R = 25 \text{ V}$ at $V_R = 75 \text{ V}$ at $V_R = 25 \text{ V}, T_j = 150^\circ\text{C}$ at $V_R = 75 \text{ V}, T_j = 150^\circ\text{C}$	$I_R$	30 1 30 50	nA $\mu\text{A}$ $\mu\text{A}$ $\mu\text{A}$
Diode Capacitance at $V_R = 0 \text{ V}, f = 1 \text{ MHz}$	$C_{tot}$	1.5	pF
Reverse Recovery Time at $I_F = I_R = 10 \text{ mA}, I_{rr} = 0.1 \times I_R, R_L = 100 \Omega$	$t_{rr}$	4	ns

## Typical Characteristics

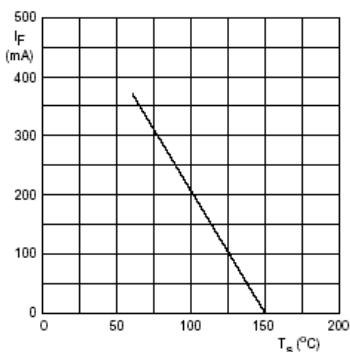


Fig. 1 Maximum permissible continuous forward current as a function of soldering point temperature.

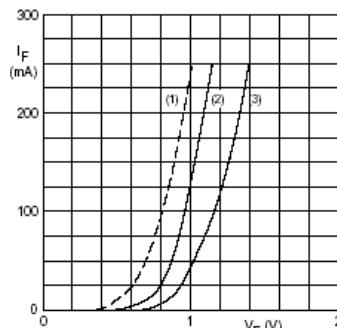
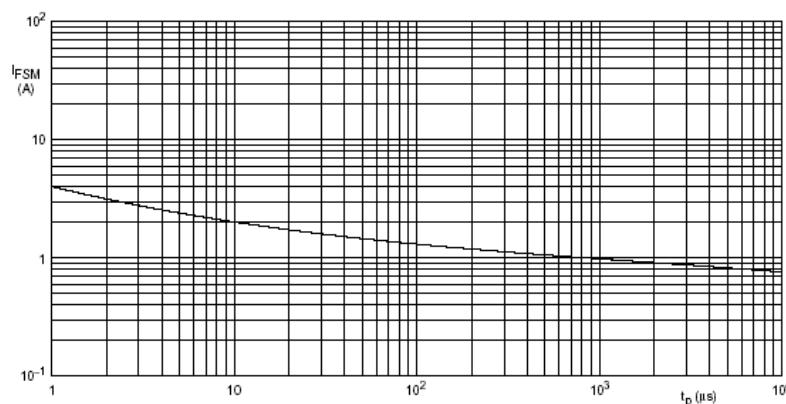


Fig. 2 Forward current as a function of forward voltage.



Based on square wave currents.  
T<sub>j</sub> = 25 °C prior to surge.

Fig. 3 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

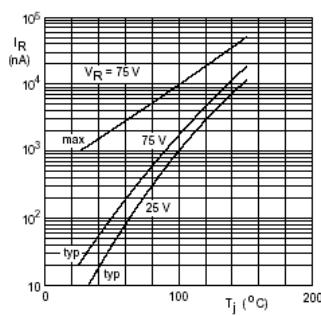


Fig. 4 Reverse current as a function of junction temperature.

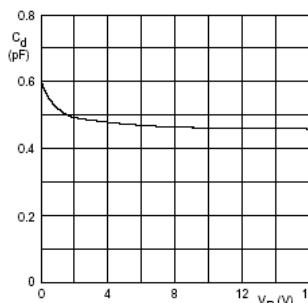


Fig. 5 Diode capacitance as a function of reverse voltage; typical values.

## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323

